



Product data sheet

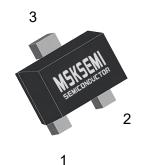
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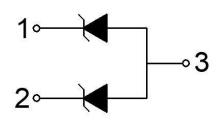


ESD7CXXDT5G-MS

Semiconductor Compiance

Appearance & Symbol





Package: SOT-723

- 1: Cathode
- 2: Cathode
- 3: Anode

Mechanical Characteristics

- Package: SOT-723
- Lead Finish:Matte Tin
- Case Material: "Green" Molding Compound.
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020

Applications

- Automotive Applications
- CAN Bus
- Electronic Control Units
- Body Control Units
- ADAS Control Units
- PowerTrain Control Units

Features

- Up to 2 lines protects
- Peak Pulse Current (8/20us):1.5A
- IEC61000-4-2 (ESD) ±15kV (air), ±8kV (contact)
- Low leakage current
- Working voltages:3.3-5V
- Qualified to AEC-Q101 Standards for High Reliability
- RoHS Compliant





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Absolute Maximum Ratings (T=25°C, RH=45%-75%, unless otherwise noted)

Parameters	Symbol	Value	Unit
Peak Pulse Current(8/20µs)	lpp	1.5	А
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	V _{ESD}	±15 ±8	ΚV
Thermal Resistance Junction-to-Ambient	R _{OJA}	525	°C/W
Operating Temperature Range	TJ	-55 to +150	°C
Storage Temperature Range	Tstg	-55 to +150	°C
Lead Solder Temperature – Maximum (10 Second Duration)	Τι	260	°C

Electrical Characteristics (T=25°C, RH=45%-75%, unless otherwise noted, VF=1.1V Max.@IF=10mA)

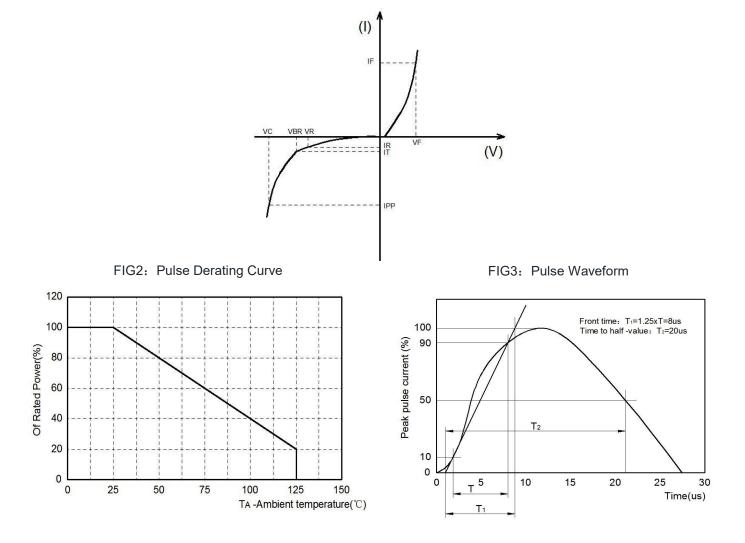
P/N MARK		VRwm	V _{BR} @I _T	IR@VR	Ι _Τ	CJ	
	max(V)	min(V)	max (uA)	(mA)	Typ(pF)	Max(pF)	
ESD7C3.3DT5G-MS	L5	3.3	5.0	1	1.0	12	13
ESD7C5.0DT5G-MS	L4	5.0	6.0	0.5	1.0	6.0	6.2





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FIG1: V-I cure characteristics



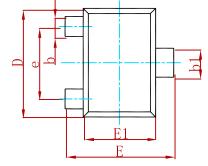
Symbol	Parameter	
IF	Mean Forward Current	
VF	Maximum Forward Voltage @I⊧	
VR	Peak Reverse Working Voltage	
I _R	Reverse Leakage Current @ V _R	
V _{BR}	Breakdown Voltage @ I⊤	
Ιτ	Test Current	
Ірр	Maximum Reverse Peak Pulse Current	
Vc	Clamping Voltage @ IPP	

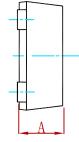


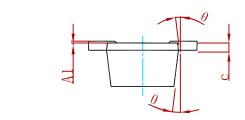
ESD7CXXDT5G-MS HF

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PACKAGE MECHANICAL DATA

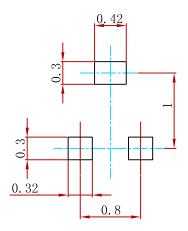






Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min.	Max.	Min.	Max.	
Α	0.430	0.500	0.017	0.020	
A1	0.000	0.050	0.000	0.002	
b	0.170	0.270	0.007	0.011	
b1	0.270	0.370	0.011	0.015	
С	0.080	0.150	0.003	0.006	
D	1.150	1.250	0.045	0.049	
E	1.150	1.250	0.045	0.049	
E1	0.750	0.850	0.030	0.033	
е	0.800TYP.		0.031TYP.		
θ	7° REF.		7° REF.		

Suggested Pad Layout



Note:

1.Controlling dimension:in millimeters.

2.General tolerance:±0.05mm.
3.The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
ESD7CXXDT5G-MS	SOT-723	8000



ESD7CXXDT5G-MS HF 🧟

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